

74AHC2G241-Q100; 74AHCT2G241-Q100

Dual buffer/line driver; 3-state

Rev. 1 — 12 November 2013

Product data sheet

1. General description

The 74AHC2G241-Q100 and 74AHCT2G241-Q100 are high-speed Si-gate CMOS devices. They provide a dual non-inverting buffer/line driver with 3-state outputs. The 3-state outputs are controlled by the output enable inputs $\overline{1OE}$ and 2OE. A HIGH level at pin $\overline{1OE}$ causes output 1Y to assume a high-impedance OFF-state. A LOW level at pin 2OE causes output 2Y to assume a high-impedance OFF-state. Schmitt-trigger action at all inputs makes the circuit highly tolerant for slower input rise and fall times.

The AHC device has CMOS input switching levels and supply voltage range 2 V to 5.5 V.

The AHCT device has TTL input switching levels and supply voltage range 4.5 V to 5.5 V.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and from $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$
- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- Multiple package options
- ESD protection:
 - ◆ MIL-STD-883, method 3015 exceeds 2000 V
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V ($C = 200\text{ pF}$, $R = 0\text{ }\Omega$)



3. Ordering information

Table 1. Ordering information

| Type number | Package | | | |
|---|-------------------|--------|--|----------|
| | Temperature range | Name | Description | Version |
| 74AHC2G241DP-Q100 74AHCT2G241DP-Q100 | −40 °C to +125 °C | TSSOP8 | plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm | SOT505-2 |
| 74AHC2G241DC-Q100 74AHCT2G241DC-Q100 | −40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm | SOT765-1 |

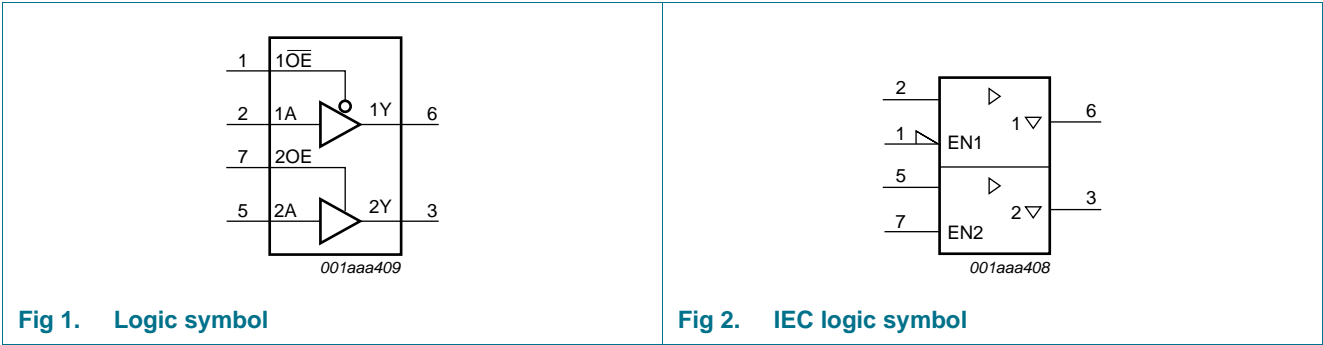
4. Marking

Table 2. Marking

| Type number | Marking code ^[1] |
|--------------------|-----------------------------|
| 74AHC2G241DP-Q100 | A241 |
| 74AHCT2G241DP-Q100 | C241 |
| 74AHC2G241DC-Q100 | A41 |
| 74AHCT2G241DC-Q100 | C41 |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning

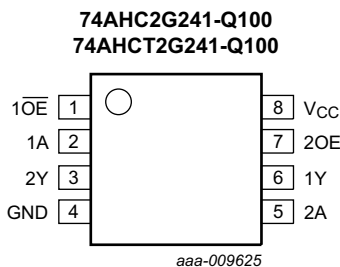


Fig 3. Pin configuration SOT505-2 (TSSOP8) and SOT765-1 (VSSOP8)

6.2 Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|------------------|-----|-----------------------------------|
| $\overline{1OE}$ | 1 | output enable input (active LOW) |
| 1A | 2 | data input |
| 2Y | 3 | data output |
| GND | 4 | ground (0 V) |
| 2A | 5 | data input |
| 1Y | 6 | data output |
| 2OE | 7 | output enable input (active HIGH) |
| V _{CC} | 8 | supply voltage |

7. Functional description

Table 4. Function table^[1]

| Input | | Output | Input | | Output |
|------------------|----|--------|-------|----|--------|
| $\overline{1OE}$ | 1A | 1Y | 2OE | 2A | 2Y |
| L | L | L | H | L | L |
| L | H | H | H | H | H |
| H | X | Z | L | X | Z |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|--|---------|----------|------|
| V_{CC} | supply voltage | | -0.5 | +7.0 | V |
| V_I | input voltage | | -0.5 | +7.0 | V |
| I_{IK} | input clamping current | $V_I < -0.5$ V | [1] -20 | - | mA |
| I_{OK} | output clamping current | $V_O < -0.5$ V or $V_O > V_{CC} + 0.5$ V | [1] - | ± 20 | mA |
| I_O | output current | -0.5 V $< V_O < V_{CC} + 0.5$ V | - | ± 25 | mA |
| I_{CC} | supply current | | - | 75 | mA |
| I_{GND} | ground current | | -75 | - | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| P_{tot} | total power dissipation | $T_{amb} = -40$ °C to +125 °C | [2] - | 250 | mW |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP8 package: above 55 °C the value of P_{tot} derates linearly with 2.5 mW/K.
For VSSOP8 package: above 110 °C the value of P_{tot} derates linearly with 8 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | 74AHC2G241-Q100 | | | 74AHCT2G241-Q100 | | | Unit |
|---------------------|-------------------------------------|------------------------------|-----------------|-----|----------|------------------|-----|----------|------|
| | | | Min | Typ | Max | Min | Typ | Max | |
| V_{CC} | supply voltage | | 2.0 | 5.0 | 5.5 | 4.5 | 5.0 | 5.5 | V |
| V_I | input voltage | | 0 | - | 5.5 | 0 | - | 5.5 | V |
| V_O | output voltage | | 0 | - | V_{CC} | 0 | - | V_{CC} | V |
| T_{amb} | ambient temperature | | -40 | +25 | +125 | -40 | +25 | +125 | °C |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 3.3$ V ± 0.3 V | - | - | 100 | - | - | - | ns/V |
| | | $V_{CC} = 5.0$ V ± 0.5 V | - | - | 20 | - | - | 20 | ns/V |

10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | 25 °C | | | –40 °C to +85 °C | | –40 °C to +125 °C | | Unit |
|------------------|---------------------------|--|-------|-----|------|------------------|------|-------------------|------|------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| 74AHC2G241-Q100 | | | | | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 2.0 V | 1.5 | - | - | 1.5 | - | 1.5 | - | V |
| | | V _{CC} = 3.0 V | 2.1 | - | - | 2.1 | - | 2.1 | - | V |
| | | V _{CC} = 5.5 V | 3.85 | - | - | 3.85 | - | 3.85 | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 2.0 V | - | - | 0.5 | - | 0.5 | - | 0.5 | V |
| | | V _{CC} = 3.0 V | - | - | 0.9 | - | 0.9 | - | 0.9 | V |
| | | V _{CC} = 5.5 V | - | - | 1.65 | - | 1.65 | - | 1.65 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | | | | | |
| | | I _O = –50 µA; V _{CC} = 2.0 V | 1.9 | 2.0 | - | 1.9 | - | 1.9 | - | V |
| | | I _O = –50 µA; V _{CC} = 3.0 V | 2.9 | 3.0 | - | 2.9 | - | 2.9 | - | V |
| | | I _O = –50 µA; V _{CC} = 4.5 V | 4.4 | 4.5 | - | 4.4 | - | 4.4 | - | V |
| | | I _O = –4.0 mA; V _{CC} = 3.0 V | 2.58 | - | - | 2.48 | - | 2.40 | - | V |
| | | I _O = –8.0 mA; V _{CC} = 4.5 V | 3.94 | - | - | 3.8 | - | 3.70 | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | | | | | |
| | | I _O = 50 µA; V _{CC} = 2.0 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I _O = 50 µA; V _{CC} = 3.0 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I _O = 50 µA; V _{CC} = 4.5 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.36 | - | 0.44 | - | 0.55 | V |
| | | I _O = 8.0 mA; V _{CC} = 4.5 V | - | - | 0.36 | - | 0.44 | - | 0.55 | V |
| I _{OZ} | OFF-state output current | V _I = V _{CC} or GND; V _{CC} = 5.5 V | - | - | 0.25 | - | 2.5 | - | 10 | µA |
| I _I | input leakage current | V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V | - | - | 0.1 | - | 1.0 | - | 2.0 | µA |
| I _{CC} | supply current | V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V | - | - | 1.0 | - | 10 | - | 40 | µA |
| C _I | input capacitance | | - | 1.5 | 10 | - | 10 | - | 10 | pF |
| 74AHCT2G241-Q100 | | | | | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 4.5 V to 5.5 V | 2.0 | - | - | 2.0 | - | 2.0 | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 4.5 V to 5.5 V | - | - | 0.8 | - | 0.8 | - | 0.8 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V | | | | | | | | |
| | | I _O = –50 µA | 4.4 | 4.5 | - | 4.4 | - | 4.4 | - | V |
| | | I _O = –8.0 mA | 3.94 | - | - | 3.8 | - | 3.70 | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V | | | | | | | | |
| | | I _O = 50 µA | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I _O = 8.0 mA | - | - | 0.36 | - | 0.44 | - | 0.55 | V |

Table 7. Static characteristics ...continued
 Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|-----------------|---------------------------|--|-------|-----|------|------------------|-----|-------------------|-----|---------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| I_{OZ} | OFF-state output current | $V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V | - | - | 0.25 | - | 2.5 | - | 10 | μ A |
| I_I | input leakage current | $V_I = 5.5$ V or GND; $V_{CC} = 0$ V to 5.5 V | - | - | 0.1 | - | 1.0 | - | 2.0 | μ A |
| I_{CC} | supply current | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V | - | - | 1.0 | - | 10 | - | 40 | μ A |
| ΔI_{CC} | additional supply current | per input pin; $V_I = 3.4$ V; other inputs at V_{CC} or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V | - | - | 1.35 | - | 1.5 | - | 1.5 | mA |
| C_I | input capacitance | | - | 1.5 | 10 | - | 10 | - | 10 | pF |

11. Dynamic characteristics

Table 8. Dynamic characteristics
 GND = 0 V; for test circuit see [Figure 7](#).

| Symbol | Parameter | Conditions | 25 °C | | | −40 °C to +85 °C | | −40 °C to +125 °C | | Unit |
|---|---------------------|--|---------------------|---|---------------------|------------------|------|-------------------|------|------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| 74AHC2G241-Q100 | | | | | | | | | | |
| t _{pd} | propagation delay | nA to nY; see Figure 4 | [1] | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | [2] | | | | | | | |
| | | C _L = 15 pF | - | 4.7 | 8.0 | 1.0 | 9.5 | 1.0 | 11.5 | ns |
| | | C _L = 50 pF | - | 6.6 | 11.5 | 1.0 | 13.0 | 1.0 | 14.5 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | [3] | | | | | | | |
| | | C _L = 15 pF | - | 3.4 | 5.5 | 1.0 | 6.5 | 1.0 | 7.0 | ns |
| | | C _L = 50 pF | - | 4.7 | 7.5 | 1.0 | 8.5 | 1.0 | 9.5 | ns |
| | | t _{en} | enable time | 1OE to 1Y; see Figure 5 | [1] | | | | | |
| V _{CC} = 3.0 V to 3.6 V | [2] | | | | | | | | | |
| C _L = 15 pF | - | | | 5.0 | 8.0 | 1.0 | 9.5 | 1.0 | 11.5 | ns |
| C _L = 50 pF | - | | | 6.9 | 11.5 | 1.0 | 13.0 | 1.0 | 14.5 | ns |
| V _{CC} = 4.5 V to 5.5 V | [3] | | | | | | | | | |
| C _L = 15 pF | - | | | 3.6 | 5.1 | 1.0 | 6.0 | 1.0 | 6.5 | ns |
| C _L = 50 pF | - | | | 4.9 | 7.5 | 1.0 | 8.5 | 1.0 | 9.5 | ns |
| 2OE to 2Y; see Figure 6 | [1] | | | | | | | | | |
| V _{CC} = 3.0 V to 3.6 V | [2] | | | | | | | | | |
| C _L = 15 pF | - | | | 4.9 | 8.0 | 1.0 | 9.5 | 1.0 | 10.0 | ns |
| C _L = 50 pF | - | | | 7.0 | 11.5 | 1.0 | 13.0 | 1.0 | 14.5 | ns |
| V _{CC} = 4.5 V to 5.5 V | [3] | | | | | | | | | |
| C _L = 15 pF | - | | | 3.6 | 5.6 | 1.0 | 6.3 | 1.0 | 7.0 | ns |
| C _L = 50 pF | - | | | 5.4 | 8.0 | 1.0 | 9.0 | 1.0 | 9.5 | ns |

Table 8. Dynamic characteristics ...continued
GND = 0 V; for test circuit see Figure 7.

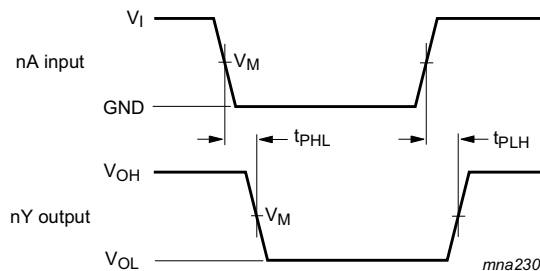
| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|-------------------------|-------------------------------|--|-------|-----|------|------------------|------|-------------------|------|------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| t_{dis} | disable time | $1\overline{OE}$ to 1Y; see Figure 5 [1] | | | | | | | | |
| | | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ [2] | | | | | | | | |
| | | $C_L = 15\text{ pF}$ | - | 6.0 | 9.7 | 1.0 | 11.5 | 1.0 | 12.5 | ns |
| | | $C_L = 50\text{ pF}$ | - | 8.3 | 13.2 | 1.0 | 15.0 | 1.0 | 16.5 | ns |
| | | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ [3] | | | | | | | | |
| | | $C_L = 15\text{ pF}$ | - | 4.1 | 6.8 | 1.0 | 8.0 | 1.0 | 8.5 | ns |
| | | $C_L = 50\text{ pF}$ | - | 5.7 | 8.8 | 1.0 | 10.0 | 1.0 | 11.0 | ns |
| | | 2OE to 2Y; see Figure 6 [1] | | | | | | | | |
| | | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ [2] | | | | | | | | |
| | | $C_L = 15\text{ pF}$ | - | 6.3 | 9.7 | 1.0 | 11.5 | 1.0 | 12.5 | ns |
| | | $C_L = 50\text{ pF}$ | - | 9.0 | 13.2 | 1.0 | 15.0 | 1.0 | 16.5 | ns |
| | | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ [3] | | | | | | | | |
| | | $C_L = 15\text{ pF}$ | - | 4.3 | 6.8 | 1.0 | 8.0 | 1.0 | 8.5 | ns |
| | | $C_L = 50\text{ pF}$ | - | 6.1 | 8.8 | 1.0 | 10.0 | 1.0 | 11.0 | ns |
| C_{PD} | power dissipation capacitance | per buffer; $C_L = 50\text{ pF}$; $f_i = 1\text{ MHz}$; $V_I = \text{GND to }V_{CC}$ [4] | - | 10 | - | - | - | - | - | pF |
| 74AHCT2G241-Q100 | | | | | | | | | | |
| t_{pd} | propagation delay | nA to nY; see Figure 4 [1] | | | | | | | | |
| | | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ [3] | | | | | | | | |
| | | $C_L = 15\text{ pF}$ | - | 3.4 | 5.5 | 1.0 | 6.5 | 1.0 | 7.0 | ns |
| | | $C_L = 50\text{ pF}$ | - | 4.7 | 7.5 | 1.0 | 8.5 | 1.0 | 9.5 | ns |
| t_{en} | enable time | $1\overline{OE}$ to 1Y; see Figure 5 [1] | | | | | | | | |
| | | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ [3] | | | | | | | | |
| | | $C_L = 15\text{ pF}$ | - | 3.9 | 5.1 | 1.0 | 6.0 | 1.0 | 6.5 | ns |
| | | $C_L = 50\text{ pF}$ | - | 5.1 | 7.5 | 1.0 | 8.5 | 1.0 | 9.5 | ns |
| | | 2OE to 2Y; see Figure 6 [1] | | | | | | | | |
| | | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ [3] | | | | | | | | |
| | | $C_L = 15\text{ pF}$ | - | 3.4 | 5.6 | 1.0 | 6.3 | 1.0 | 6.5 | ns |
| | | $C_L = 50\text{ pF}$ | - | 4.8 | 7.5 | 1.0 | 9.0 | 1.0 | 9.5 | ns |

Table 8. Dynamic characteristics ...continued
GND = 0 V; for test circuit see Figure 7.

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|-----------|-------------------------------|--|-------|-----|-----|------------------|------|-------------------|------|------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| t_{dis} | disable time | $1\overline{OE}$ to 1Y; see Figure 5 [1] | | | | | | | | |
| | | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ [3] | | | | | | | | |
| | | $C_L = 15\text{ pF}$ | - | 4.5 | 6.8 | 1.0 | 8.0 | 1.0 | 8.5 | ns |
| | | $C_L = 50\text{ pF}$ | - | 6.1 | 8.8 | 1.0 | 10.0 | 1.0 | 11.0 | ns |
| | | 2OE to 2Y; see Figure 6 [1] | | | | | | | | |
| | | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ [3] | | | | | | | | |
| | | $C_L = 15\text{ pF}$ | - | 4.0 | 6.8 | 1.0 | 8.0 | 1.0 | 8.5 | ns |
| | | $C_L = 50\text{ pF}$ | - | 5.7 | 8.8 | 1.0 | 10.0 | 1.0 | 11.0 | ns |
| C_{PD} | power dissipation capacitance | per buffer; $C_L = 50\text{ pF}$; $f_i = 1\text{ MHz}$; $V_I = \text{GND to }V_{CC}$ | [4] | - | 10 | - | - | - | - | pF |

- [1] t_{pd} is the same as t_{PLH} and t_{PHL} .
 t_{en} is the same as t_{PZL} and t_{PZH} .
 t_{dis} is the same as t_{PLZ} and t_{PHZ} .
- [2] Typical values are measured at $V_{CC} = 3.3\text{ V}$.
- [3] Typical values are measured at $V_{CC} = 5.0\text{ V}$.
- [4] C_{PD} is used to determine the dynamic power dissipation P_D (μW).
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz;
 f_o = output frequency in MHz;
 C_L = output load capacitance in pF;
 V_{CC} = supply voltage in V.

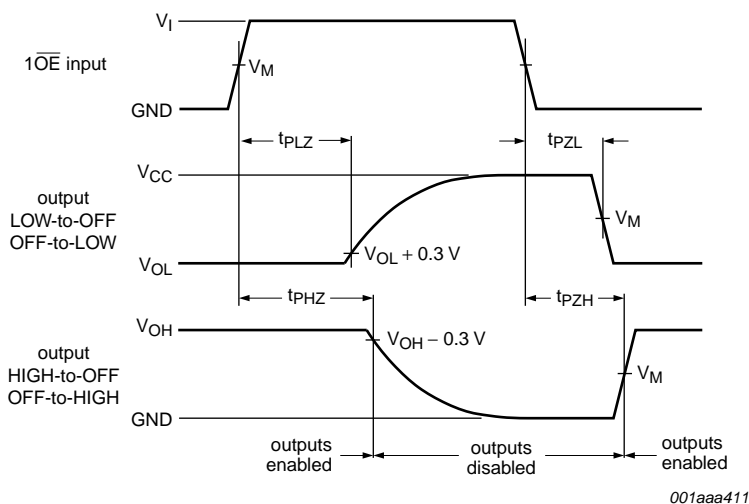
12. Waveforms and test circuit



Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

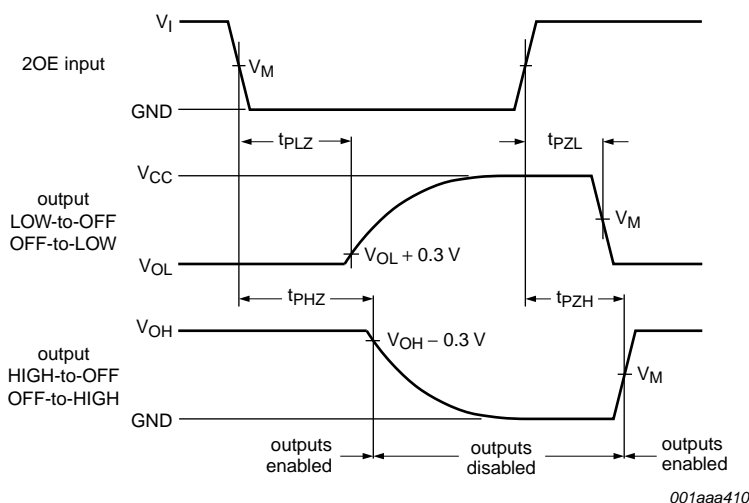
Fig 4. The input (nA) to output (nY) propagation delays



Measurement points are given in [Table 9](#).

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 5. The input (1OE) to output (1Y) enable and disable times



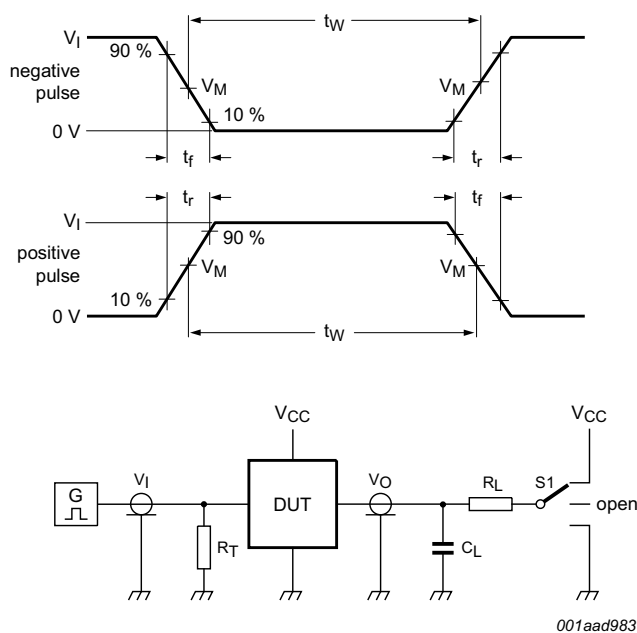
Measurement points are given in [Table 9](#).

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 6. The input (2OE) to output (2Y) enable and disable times

Table 9. Measurement points

| Type | Input | Output |
|------------------|-------------|-------------|
| | V_M | V_M |
| 74AHC2G241-Q100 | $0.5V_{CC}$ | $0.5V_{CC}$ |
| 74AHCT2G241-Q100 | 1.5 V | $0.5V_{CC}$ |



Test data is given in [Table 10](#).

Definitions test circuit:

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

S1 = Test selection switch.

Fig 7. Test circuit for measuring switching times

Table 10. Test data

| Type | Input | | Load | | S1 position | | |
|------------------|----------|-------------|--------------|--------------|--------------------|--------------------|--------------------|
| | V_I | t_r, t_f | C_L | R_L | t_{PHL}, t_{PLH} | t_{PZH}, t_{PHZ} | t_{PZL}, t_{PLZ} |
| 74AHC2G241-Q100 | V_{CC} | ≤ 3 ns | 15 pF, 50 pF | 1 k Ω | open | GND | V_{CC} |
| 74AHCT2G241-Q100 | 3 V | ≤ 3 ns | 15 pF, 50 pF | 1 k Ω | open | GND | V_{CC} |

13. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2

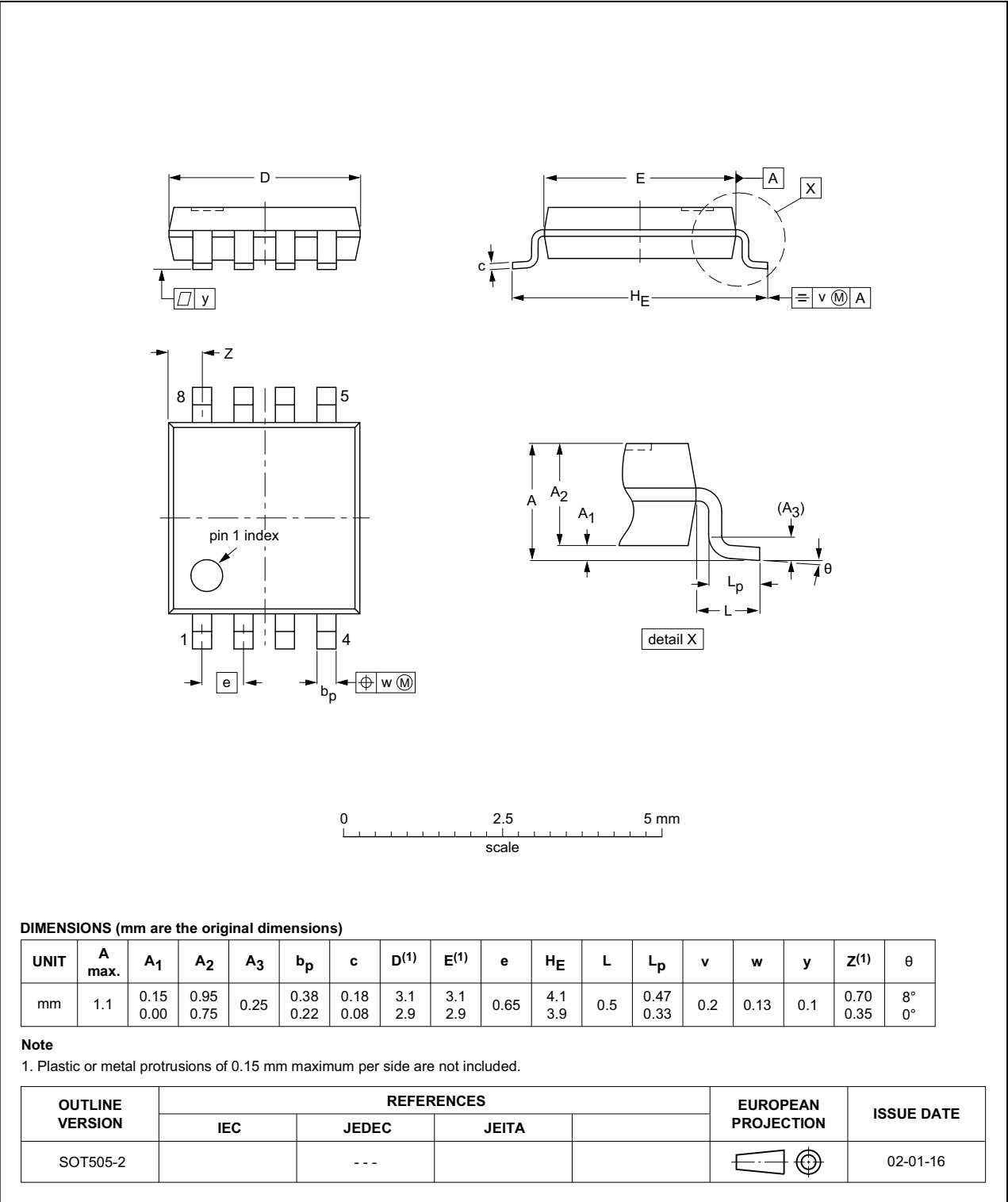
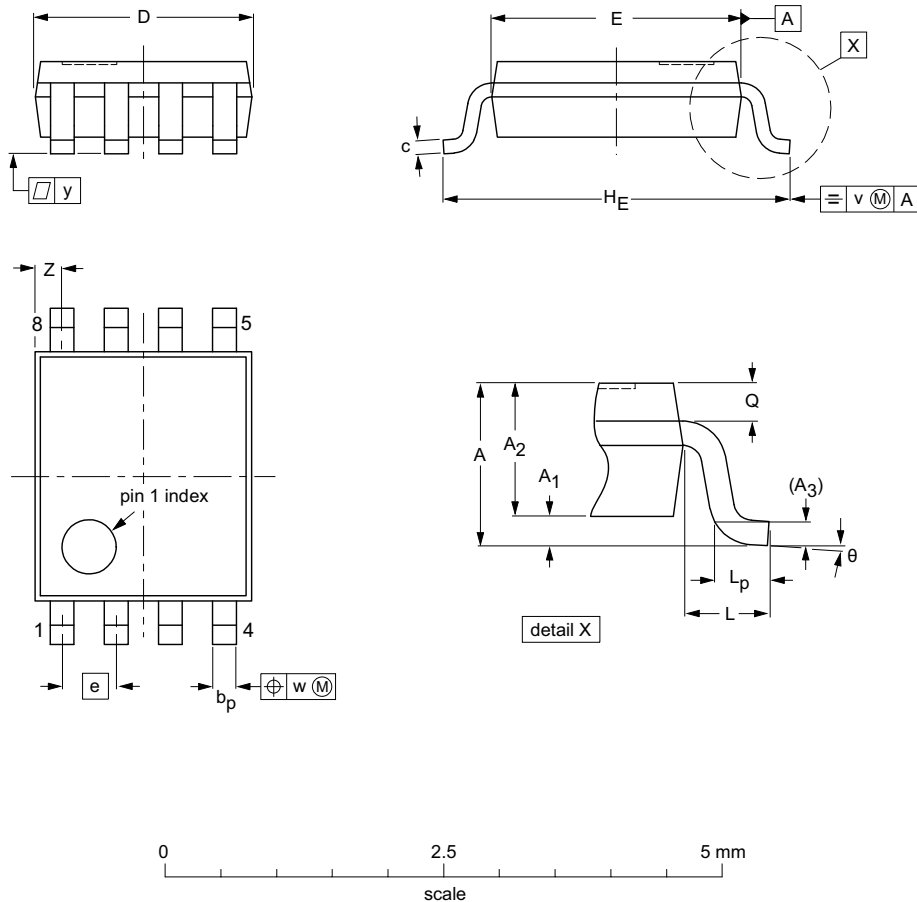


Fig 8. Package outline SOT505-2 (TSSOP8)

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1

**DIMENSIONS (mm are the original dimensions)**

| UNIT | A _{max.} | A ₁ | A ₂ | A ₃ | b _p | c | D ⁽¹⁾ | E ⁽²⁾ | e | H _E | L | L _p | Q | v | w | y | Z ⁽¹⁾ | θ |
|------|-------------------|----------------|----------------|----------------|----------------|--------------|------------------|------------------|-----|----------------|-----|----------------|--------------|-----|------|-----|------------------|----------|
| mm | 1 | 0.15 0.00 | 0.85 0.60 | 0.12 | 0.27 0.17 | 0.23 0.08 | 2.1 1.9 | 2.4 2.2 | 0.5 | 3.2 3.0 | 0.4 | 0.40 0.15 | 0.21 0.19 | 0.2 | 0.13 | 0.1 | 0.4 0.1 | 8° 0° |

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.


| OUTLINE VERSION | REFERENCES | | | | EUROPEAN PROJECTION | ISSUE DATE |
|--------------------|------------|--------|-------|--|---|------------|
| | IEC | JEDEC | JEITA | | | |
| SOT765-1 | | MO-187 | | |  | 02-06-07 |

Fig 9. Package outline SOT765-1 (VSSOP8)

14. Abbreviations

Table 11. Abbreviations

| Acronym | Description |
|---------|-----------------------------|
| CDM | Charged Device Model |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MIL | Military |
| MM | Machine Model |
| TTL | Transistor-Transistor Logic |

15. Revision history

Table 12. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|--------------------------|--------------|--------------------|---------------|------------|
| 74AHC_AHCT2G241_Q100 v.1 | 20131112 | Product data sheet | - | - |

16. Legal information

16.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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